

1.2MHZ, 14V Step-up DC/DC Converter

GENERAL DESCRIPTION

The PT F111 is a high frequency, high efficiency DC to DC converter with an integrated 4A, 0.1 Ω power switch capable of providing an output voltage up to 14V. The fixed 1.2MHz allows the use of small external inductions and capacitors and provides fast transient response. It integrates Soft start, Comp., only need few components outside.

It can be adjusted SW current limit by one resistor or one analog voltage.

FEATURES

- 2.3V to 6V input voltage Rangel
- Efficiency up to 96%
- 14V Boost converter with adjusted switch current
- 1.2Mhz fixed Switching Frequency
- Integrated soft-start
- Adjustable current limit
- Thermal Shutdown
- Under voltage Lockout
- SOT23-6 Package

APPLICATIONS

- Handheld Devices
- GPS Receiver
- Digital Still Camera
- Portable Applications
- DSL Modem
- PCMCIA Card
- TFT LCD Bias Supply

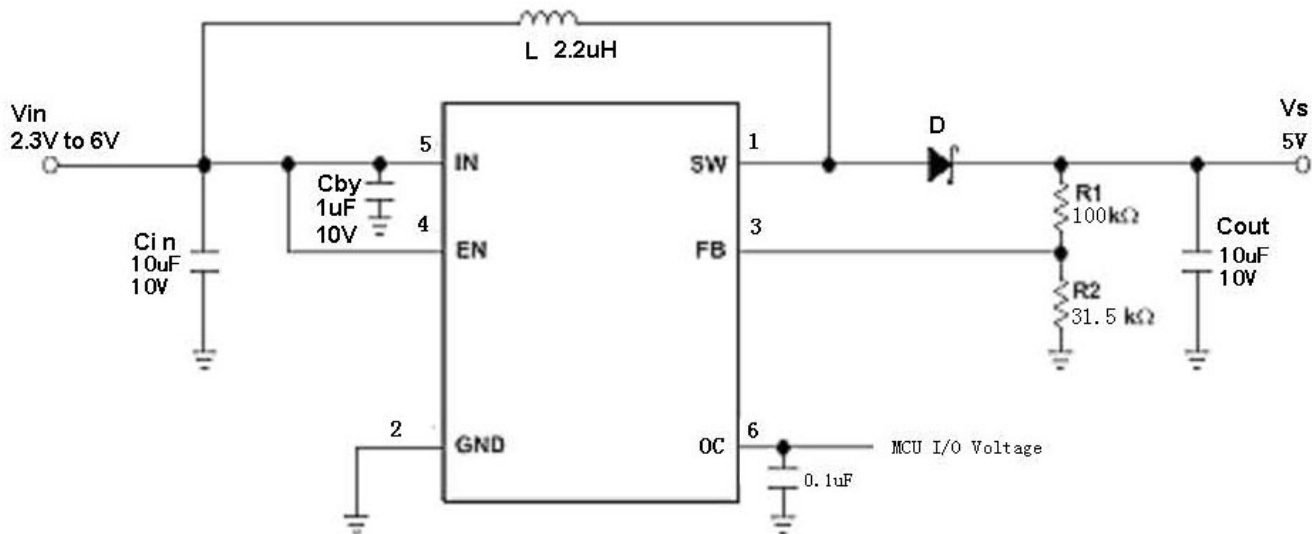


Figure 1. Typical Application Circuit1

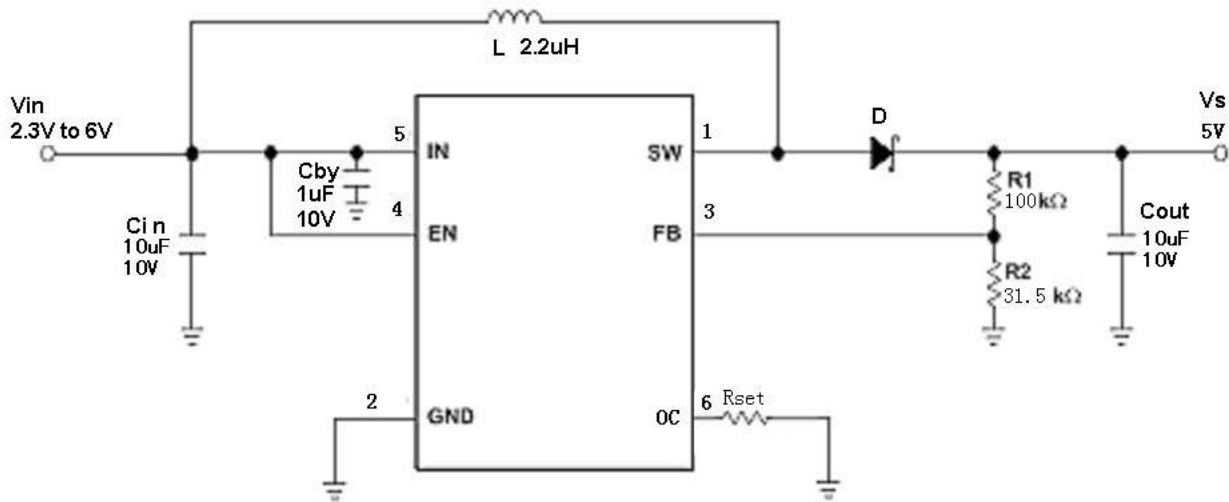


Figure 2. Typical Application Circuit2

ORDERING INFORMATION

PART NUMBER	TEMP RANGE	SWICHING FREQUENCY	OUTPUT VOLTAGE (V)	ILIM (A)	PACKAGE	PINS
ATF11	-40°C to 85°C	100kHz	1.2V	1.0A	UUVG-E	6

PIN CONFIGURATION

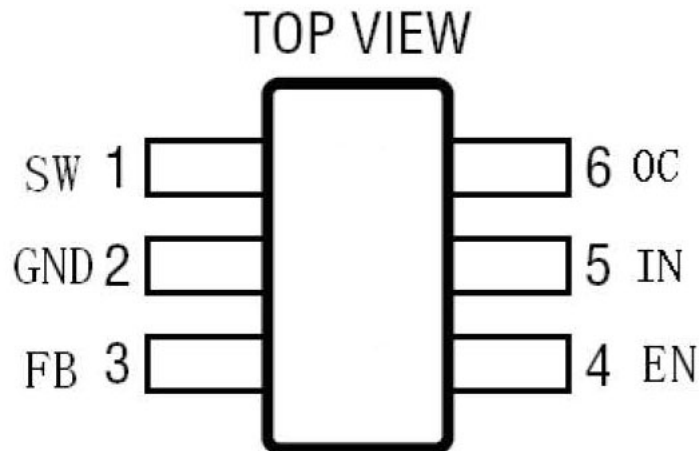


Figure 3. PIN Configuration

PIN DESCRIPTION

PIN NUMBER	PIN NAME	PIN DESCRIPTION
1	SW	Switch pin
2	GND	Ground
3	FB	Feedback pin
4	EN	Shutdown control input., Connect this pin to logic high level to enable the device
5	IN	Input power supply pin
6	OC	SW current limit setting pin, Set current limit by Rset or analog voltage

ABSOLUTE MAXIMUM RATINGS

(Note: Do not exceed these limits to prevent damage to the device. Exposure to absolute maximum rating conditions for long periods may affect device reliability.)

PARAMETER	VALUE	UNIT
Supply Voltage VIN	-0.3 to 6.5	V
FB, EN Voltage	-0.3 to VIN+0.3	V
SW Voltage	Vin+0.3 to 15V	V
Operating Ambient Temperature	-40 to 85	°C
Maximum Junction Temperature	150	°C
Storage Temperature	-55 to 150	°C
Lead Temperature (Soldering, 10 sec)	300	°C

ELECTRICAL CHARACTERISTICS

(VIN = 3.6V, TA = 25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage Range	VIN		2.3		6.0	V
Boost output voltage range	Vout		14			V
UVLO Threshold	VUVLO	VHYSTERESIS =100mV	2.1	2.2	2.3	V
Operating Supply Current	ISUPPLY	VFB =1.3V, EN=Vin, ILoad =0		75	135	µA
Shutdown Supply Current		VEN =0V, VIN =4.2V		0.1	1	
Regulated Feedback Voltage	VFB		1.188	1.2	1.212	V

Peak Inductor Current limit (N-MOSFET Current limit)	I_{lim}	Voc=0.50V Vin=3.6V Vout=5V	0.8	0.95	1.1	A
Peak Inductor Current limit (N-MOSFET Current limit)	I_{lim}	Voc=0.60V Vin=3.6V Vout=5V	1.5	1.75	2.0	A
Peak Inductor Current limit (N-MOSFET Current limit)	I_{lim}	Rset=168K Vin=3.6V Vout=5V	1.8	2.2	2.6	A
Peak Inductor Current limit (N-MOSFET Current limit)	I_{lim}	Rset=120K Vin=3.6V Vout=5V	1.05	1.3	2.55	A
Oscillator Frequency	F_{osc}		0.9	1.2	1.5	MHz
Rds(ON) of N-channel FET		$I_{SW} = -100mA$		0.1	0.2	Ohm
Enable Threshold		$V_{IN} = 2.3V \text{ to } 5.5V$	0.3	1	1.5	V
Enable Leakage Current			-0.1		0.1	μA
SW Leakage Current		$V_{EN} = 0V, V_{SW} = 0V \text{ or } 5V, V_{IN} = 5V$			1	μA

DETAILED DESCRIPTION

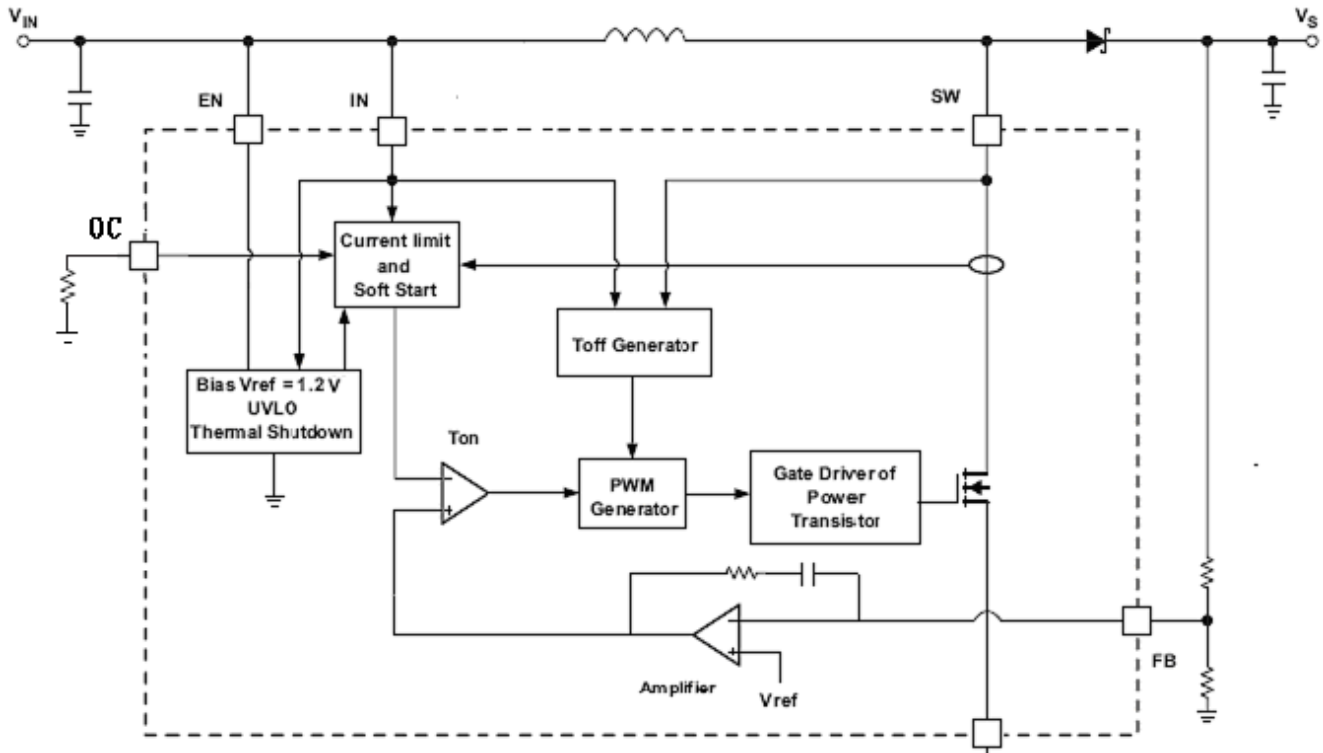


Figure 4. Functional Block Diagram

FUNCTIONAL DESCRIPTION

NORMAL OPERATION

The boost converter is designed for output voltage up to 14V with a switch MAX peak current limit of 4 A. The device, which operates in a current mode scheme with quasi-constant frequency, is externally 1.2MHz and the minimum input voltage is 2.3 V. To control the inrush current at start-up a soft-start pin is available.

During the on-time, the voltage across the inductor causes the current in it to rise. When the current reaches a threshold value set by the internal GM amplifier, the power transistor is turned off, the energy stored into the inductor is then released and the current flows through the Schottky diode towards the output of the boost converter. The off-time is fixed for a certain V_{in} and V_s , and therefore maintains the same frequency when varying these parameters.

However, for different output loads, the

frequency may slightly change due to the voltage drop across the R_{dson} of the power transistor which will have an effect on the voltage across the inductor and thus on T_{on} (T_{off} remains fixed). Some slight frequency changes might also appear with a fixed output load due to the fact that the output voltage V_s is not sensed directly but via the SW Pin, which affects accuracy.

Because of the quasi-constant frequency behavior of the device, the PTFIII eliminates the need for an internal oscillator and slope compensation, which provides better stability for the system over a wide of input and output voltages range, and more stable and accurate current limiting operation compared to boost converters operating with a conventional PWM scheme. The PTFIII topology has also the benefits of providing very good load and line regulations, and excellent load transient response.

UNDERVOLTAGE LOCKOUT (UVLO)

To avoid mis-operation of the device at low input voltages an under voltage lockout is included that disables the device, if the input voltage falls below 2.2V

THERMAL SHUTDOWN

A thermal shutdown is implemented to prevent damages due to excessive heat and power dissipation. Typically the thermal shutdown threshold is 150°C .When the thermal shutdown is triggered the device stops switching until the temperature falls below typically 136 °C .Then the device starts switching again.

APPLICATION INFORMATION

INDUCTOR SELECTION

In normal operation, the inductor maintains continuous current to the output. The inductor current has a ripple that is dependent on the inductance value. The high inductance reduces the ripple current.

Selected inductor by actual application:

Manufacturer	Part Number	Inductance(uH)	DRC max (Ohms)	Dimensions L*W*H(mm3)
Murata	LQH44PN	2.2	0.049	4*4*1.7
		3.3	0.065	
		4.7	0.08	
		10	0.16	
	LQH5BP	2.2	0.030	5*5*2
		3.3	0.044	
		4.7	0.058	
		10	0.106	
TDK	SPM6530T	2.2	0.017	7.1*6.5*3
		3.3	0.027	
		4.7	0.036	
	VLP6045LT	2.2	0.020	6*6*4.5
		3.3	0.025	
		4.7	0.029	
		10	0.055	
	WURTH	74437324022	2.2	0.061
744777004		4.7	0.025	7.3*7.3*4.5

Table 1. Recommend Surface Mount Inductors

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$$R_1 = R_2 \times \left(\frac{V_{OUT}}{1.2} - 1 \right)$$

Typically choose R2=10K and determine R1 from the following equation:

OC SETTING1(SETTING CURRENT LIMIT BY ANALOG VOLTAGE)

PT F I I can be adjusted SW current limit by one analog volatage connected with OC pin just like Typical Application Circuit1. The setting sheet is as below(Vin=3.6V Vout=5V)---Only list the typical Ilim number, the actual data may be in +/- 20% above them because of some discrete data from IC and the analog voltage.

One 0.1uF capacitor need to be placed close to OC pin.

Please do not let it float.

Analog Volatge (V)	Ilim(typ)
0.75V	3.20A
0.70V	2.75A
0.65V	2.20A
0.60V	1.75A
0.55V	1.35A
0.50V	0.95A

0.45V	0.55A
0.40V	0.20A

. For 3V~4.2Vin to 5V 1A out , 0.62V~0.65V is suitable.

If the current limit exceeds 2A, maybe the IC will be go in to over temperature protection status without good layout.

OC SETTING2(SETTING CURRENT LIMIT BY ONE RESISTOR)

PTF11 can be adjusted SW current limit by one resistor connected with OC pin just like Typical Application Circuit2 . The setting sheet is as below(Vin=3.6V Vout=5V)---Only list the typical Ilim number, the actual data may be in +/- 20% above them because of some discrete data from IC and resistor.

Please do not let it float.

Rset (ohm)	Ilim(typ)
168K	2.2A
150K	1.9A
130K	1.5A
120K	1.3A
100K	0.9A

. For 3V~4.2Vin to 5V 1A out , 150K~170Kohm is suitable.

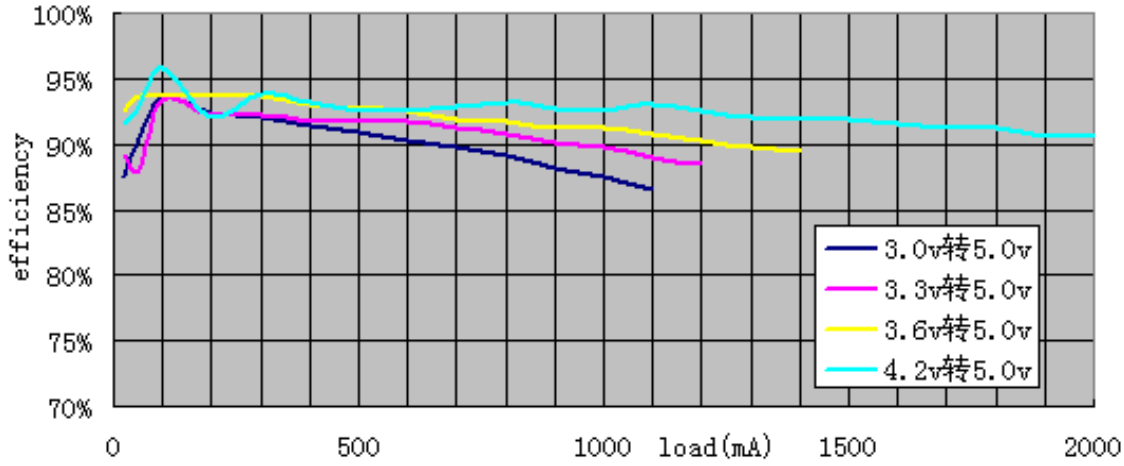
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DIODE SELECTION

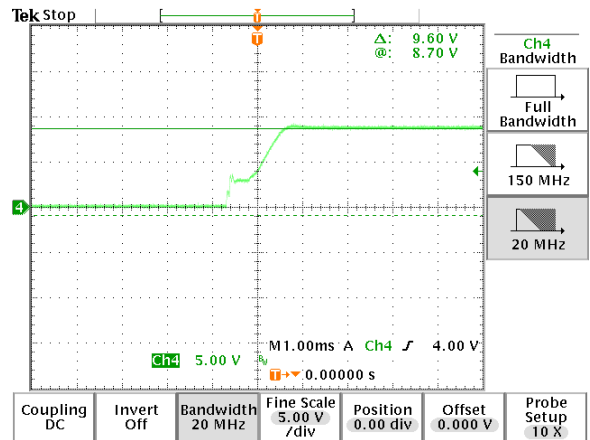
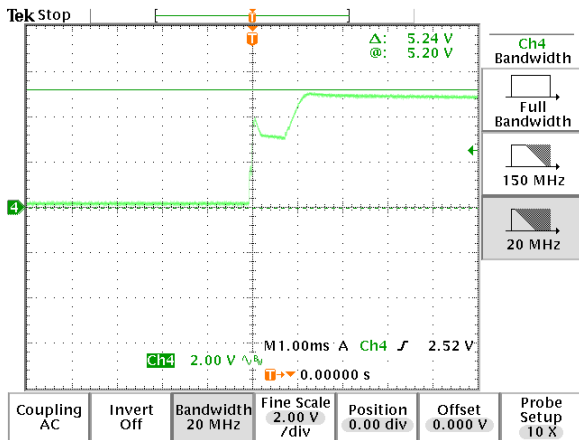
According to max Iout and max Vout, you can select suitable diode. Normally we select diode $I_f=(1.5\sim 2)*I_{outmax}$ and $V_R=(1.5\sim 2)*V_{outmax}$. For high efficiency, suggest that you select low Vf Schottky diode. ONsemi's MBRA210LT3 is prefer

TYPICAL PERFORMANCE CHARACTERISTICS

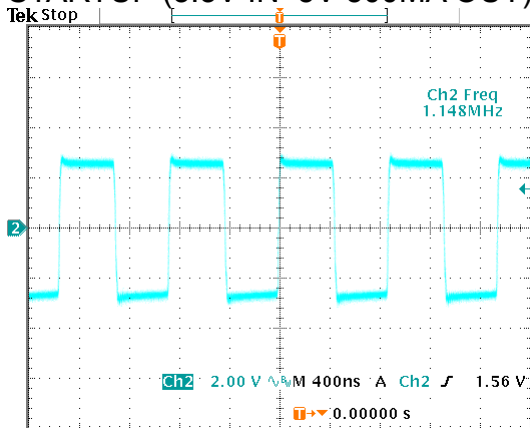
(L=2.2uH 4A, CIN=22uF, COUT=22uF, if not mentioned)



Efficiency vs. Output Current (Vout=5V Rset=168K)

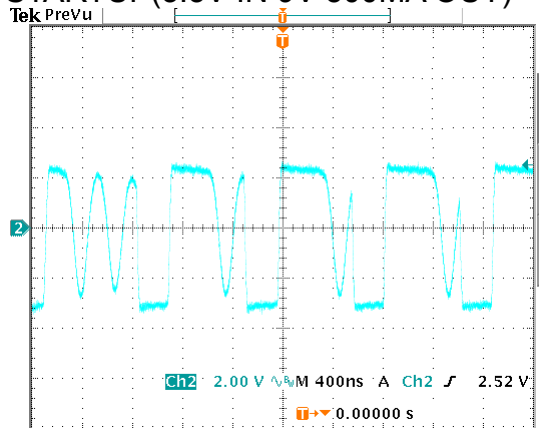


STARTUP (3.3V IN 5V 500MA OUT)



SW WAVE(3.3VIN 5V 1A OUT)

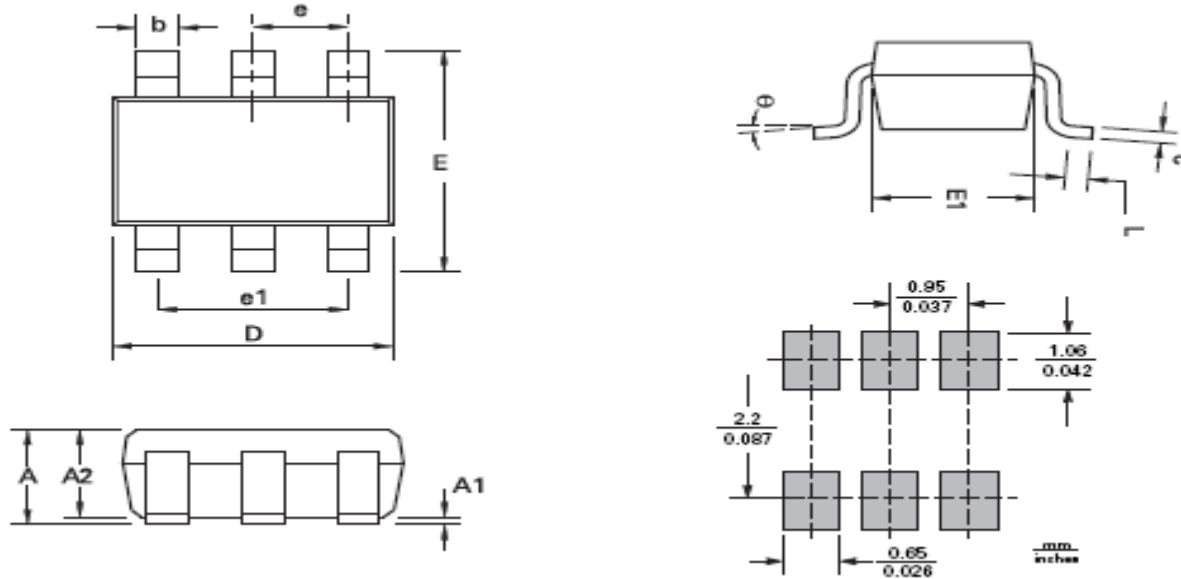
STARTUP(3.3V IN 9V 500MA OUT)



SW WAVE(3.3VIN 9V 500MA OUT)

PACKAGE OUTLINE

SOT23-6 PACKAGE OUTLINE AND DIMENSIONS



DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.90	1.45	0.0354	0.0570
A1	0.00	0.15	0.00	0.0059
A2	0.90	1.30	0.0354	0.0511
b	0.35	0.50	0.0078	0.0196
C	0.09	0.26	0.0035	0.0102
D	2.70	3.10	0.1062	0.1220
E	2.20	3.20	0.0866	0.1181
E1	1.30	1.80	0.0511	0.0708
L	0.10	0.60	0.0039	0.0236
e	0.95 REF		0.0374 REF	
e1	1.90 REF		0.0748 REF	
L	0°	30°	0°	30°

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches